# LOW-POWER CONFIGURABLE MULTIPLE-FUNCTION GATE

Check for Samples: SN74AUP1G97

FEATURES

- **Available in the Texas Instruments NanoStar™ Package**
- **Low Static-Power Consumption (I_{CC} = 0.9 µA Max)**
- **Low Dynamic-Power Consumption (C_{pd} = 4.8 pF Typ at 3.3 V)**
- **Low Input Capacitance (C_I = 1.5 pF Typ)**
- **Low Noise – Overshoot and Undershoot <10% of V_{CC}**
- **I_{off} Supports Partial-Power-Down Mode Operation**
- **Includes Schmitt-Trigger Inputs**

- **Wide Operating V_{CC} Range of 0.8 V to 3.6 V**
- **Optimized for 3.3-V Operation**
- **3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation**
- **t_{pd} = 5.6 ns Max at 3.3 V**
- **Suitable for Point-to-Point Applications**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **ESD Performance Tested Per JESD 22**
  - **2000-V Human-Body Model (A114-B, Class II)**
  - **1000-V Charged-Device Model (C101)**
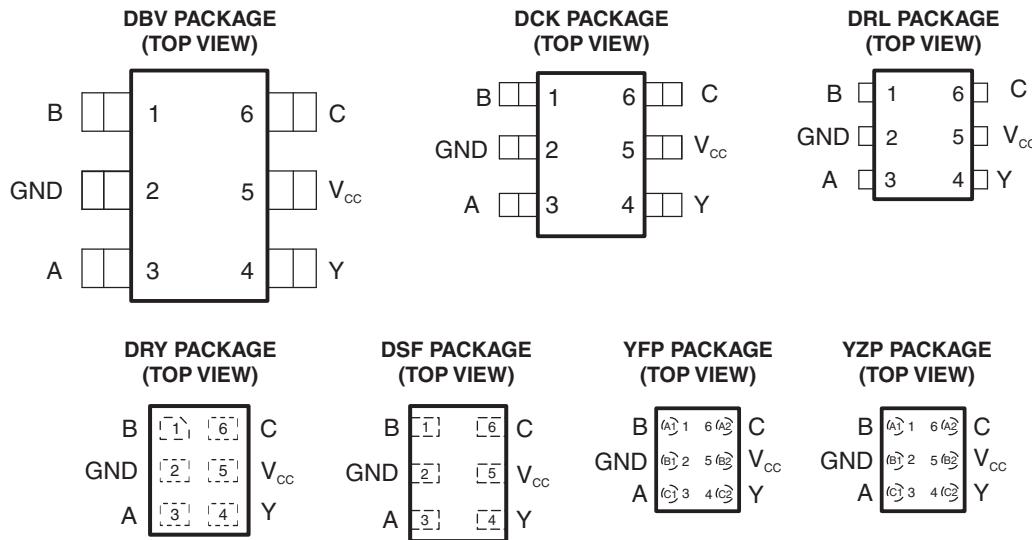

See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).

⚠️ Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Static-Power Consumption (μA)

Dynamic-Power Consumption (pF)
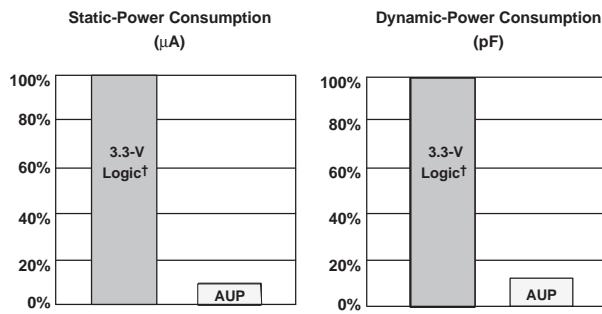
† Single, dual, and triple gates

Figure 1. AUP – The Lowest-Power Family

Switching Characteristics at 25 MHz†
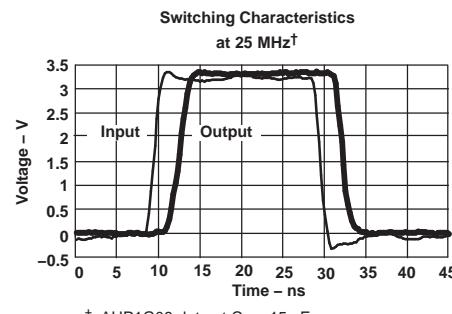
† AUP1G08 data at C_L = 15 pF

Figure 2. Excellent Signal Integrity

The SN74AUP1G97 features configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter, and noninverter. All inputs can be connected to V_{CC} or GND.

The device functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input.

NanoStar™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION[1]

T_A	PACKAGE[2]		ORDERABLE PART NUMBER	TOP-SIDE MARKING[3]
–40°C to 85°C	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP1G97YFPR	_ _ _HP_
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1G97YZPR	_ _ _HP_
	QFN – DRY	Reel of 5000	SN74AUP1G97DRYR	PREVIEW
	uQFN – DSF	Reel of 5000	SN74AUP1G97DSFR	PREVIEW
	SOT (SOT-23) – DBV	Reel of 3000	SN74AUP1G97DBVR	H97_
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP1G97DCKR	HP_
	SOT (SOT-553) – DRL	Reel of 4000	SN74AUP1G97DRLR	

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(3) DBV/DCK/DRL/DRT/DRY: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YFP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

FUNCTION TABLE

INPUTS			OUTPUT
C	B	A	Y
L	L	L	L
L	L	H	L
L	H	L	H
L	H	H	H
H	L	L	L
H	L	H	H
H	H	L	L
H	H	H	H

Product Folder Link(s): *SN74AUP1G97*

LOGIC DIAGRAM (POSITIVE LOGIC)
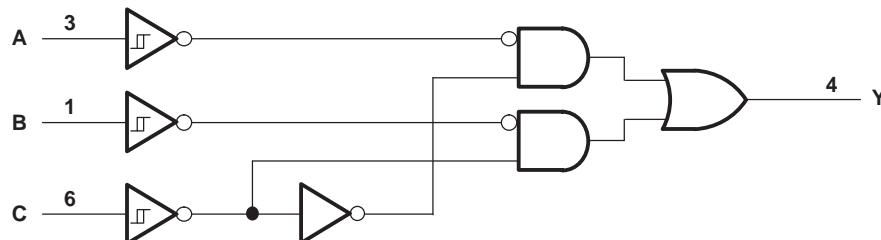
FUNCTION SELECTION TABLE

| LOGIC FUNCTION	FIGURE NO.
2-to-1 data selector	3
2-input AND gate	4
2-input OR gate with one inverted input	5
2-input NAND gate with one inverted input	5
2-input AND gate with one inverted input	6
2-input NOR gate with one inverted input	6
2-input OR gate	7
Inverter	8
Noninverted buffer	9

LOGIC CONFIGURATIONS
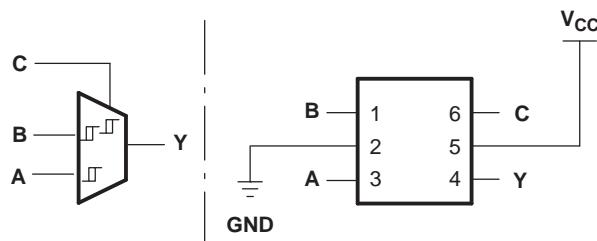
**Figure 3. 2-to-1 Data Selector**
When C is L, Y = B; When C is H, Y = A

Figure 4. 2-Input AND Gate

Product Folder Link(s): *SN74AUP1G97*
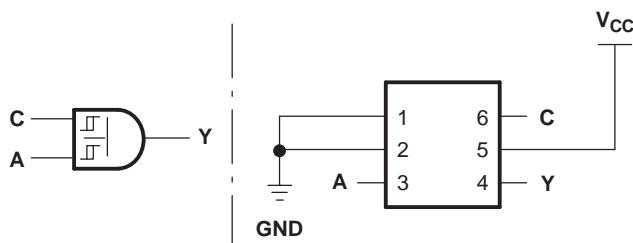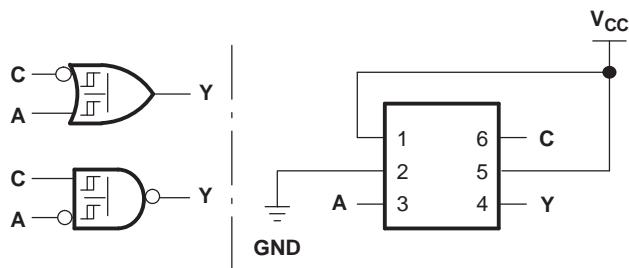
Figure 5. Input OR Gate With One Inverted Input
**2-Input NAND Gate With One Inverted Input**
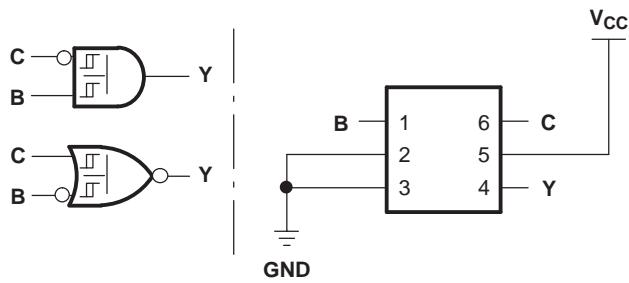
Figure 6. 2-Input AND Gate With One Inverted Input
2-Input NOR Gate With One Inverted Input
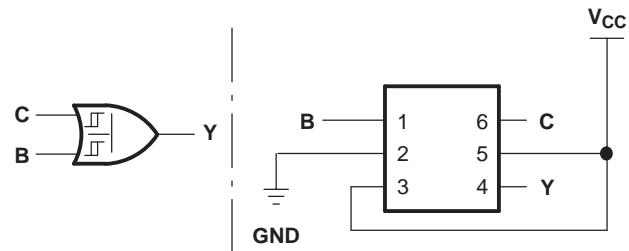
Figure 7. 2-Input OR Gate

Figure 8. Inverter

Product Folder Link(s): *SN74AUP1G97*
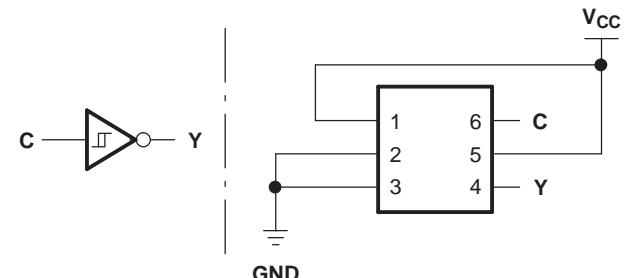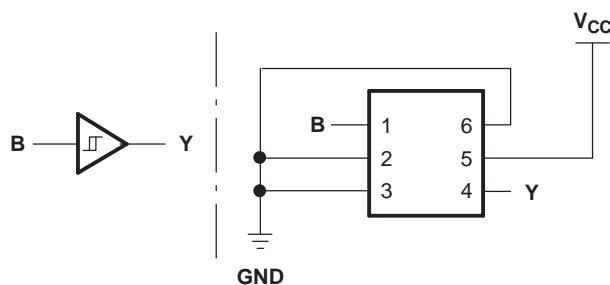
Figure 9. Noninverted Buffer

ABSOLUTE MAXIMUM RATINGS[1]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		−0.5	4.6	V
V_I	Input voltage range[2]		−0.5	4.6	V
V_O	Voltage range applied to any output in the high-impedance or power-off state[2]		−0.5	4.6	V
V_O	Output voltage range in the high or low state[2]		−0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	V_I < 0		−50	mA
I_{OK}	Output clamp current	V_O < 0		−50	mA
I_O	Continuous output current			±20	mA
	Continuous current through V_{CC} or GND			±50	mA
θ_{JA}	Package thermal impedance[3]	DBV package		165	°C/W
		DCK package		259	
		DRL package		142	
		DSF package		300	
		DRY package		234	
		YFP package		123	
		YZP package		123	
T_{stg}	Storage temperature range		−65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS[1]

			MIN	MAX	UNIT
V_{CC}	Supply voltage		0.8	3.6	V
V_I	Input voltage		0	3.6	V
V_O	Output voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 0.8 V		−20	µA
		V_{CC} = 1.1 V		−1.1	mA
		V_{CC} = 1.4 V		−1.7	
		V_{CC} = 1.65		−1.9	
		V_{CC} = 2.3 V		−3.1	
		V_{CC} = 3 V		−4	
I_{OL}	Low-level output current	V_{CC} = 0.8 V		20	µA
		V_{CC} = 1.1 V		1.1	mA
		V_{CC} = 1.4 V		1.7	
		V_{CC} = 1.65 V		1.9	
		V_{CC} = 2.3 V		3.1	
		V_{CC} = 3 V		4	
T_A	Operating free-air temperature		−40	85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Product Folder Link(s): *SN74AUP1G97*

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	T_A = 25°C			T_A = −40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
V_{T+} Positive-going input threshold voltage			0.8 V	0.3		0.6	0.3	0.6	V
			1.1 V	0.53		0.9	0.53	0.9	
			1.4 V	0.74		1.11	0.74	1.11	
			1.65 V	0.91		1.29	0.91	1.29	
			2.3 V	1.37		1.77	1.37	1.77	
			3 V	1.88		2.29	1.88	2.29	
$V_{T−}$ Negative-going input threshold voltage			0.8 V	0.1		0.6	0.1	0.6	V
			1.1 V	0.26		0.65	0.26	0.65	
			1.4 V	0.39		0.75	0.39	0.75	
			1.65 V	0.47		0.84	0.47	0.84	
			2.3 V	0.69		1.04	0.69	1.04	
			3 V	0.88		1.24	0.88	1.24	
ΔV_T Hysteresis (V_{T+} − $V_{T−}$)			0.8 V	0.07		0.5	0.07	0.5	V
			1.1 V	0.08		0.46	0.08	0.46	
			1.4 V	0.18		0.56	0.18	0.56	
			1.65 V	0.27		0.66	0.27	0.66	
			2.3 V	0.53		0.92	0.53	0.92	
			3 V	0.79		1.31	0.79	1.31	
V_{OH}		I_{OH} = −20 µA	0.8 V to 3.6 V	V_{CC} − 0.1			V_{CC} − 0.1		V
		I_{OH} = −1.1 mA	1.1 V	0.75 × V_{CC}			0.7 × V_{CC}		
		I_{OH} = −1.7 mA	1.4 V	1.11			1.03		
		I_{OH} = −1.9 mA	1.65 V	1.32			1.3		
		I_{OH} = −2.3 mA	2.3 V	2.05			1.97		
		I_{OH} = −3.1 mA		1.9			1.85		
		I_{OH} = −2.7 mA	3 V	2.72			2.67		
		I_{OH} = −4 mA		2.6			2.55		
V_{OL}		I_{OL} = 20 µA	0.8 V to 3.6 V			0.1		0.1	V
		I_{OL} = 1.1 mA	1.1 V			0.3 × V_{CC}		0.3 × V_{CC}	
		I_{OL} = 1.7 mA	1.4 V			0.31		0.37	
		I_{OL} = 1.9 mA	1.65 V			0.31		0.35	
		I_{OL} = 2.3 mA	2.3 V			0.31		0.33	
		I_{OL} = 3.1 mA				0.44		0.45	
		I_{OL} = 2.7 mA	3 V			0.31		0.33	
		I_{OL} = 4 mA				0.44		0.45	
I_I	All inputs	V_I = GND to 3.6 V	0 V to 3.6 V			0.1		0.5	µA
I_{off}		V_I or V_O = 0 V to 3.6 V	0 V			0.2		0.6	µA
ΔI_{off}		V_I or V_O = 0 V to 3.6 V	0 V to 0.2 V			0.2		0.6	µA
I_{CC}		V_I = GND or (V_{CC} to 3.6 V), I_O = 0	0.8 V to 3.6 V			0.5		0.9	µA
ΔI_{CC}		V_I = V_{CC} − 0.6 V [1], I_O = 0	3.3 V			40		50	µA
C_i		V_I = V_{CC} or GND	0 V		1.5				pF
			3.6 V		1.5				
C_o		V_O = GND	0 V		3				pF

(1) One input at V_{CC} − 0.6 V, other inputs at V_{CC} or GND.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 5 pF (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	T_A = 25°C			T_A = −40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
t_{pd}	A, B, or C	Y	0.8 V		23.1				ns
			1.2 V ± 0.1 V	3.1	9.1	13.9	2.6	17.6	
			1.5 V ± 0.1 V	2.1	6.4	9.4	1.6	11.4	
			1.8 V ± 0.15 V	1.6	5.1	7.5	1.1	9.2	
			2.5 V ± 0.2 V	1.1	3.6	5.7	0.6	6.8	
			3.3 V ± 0.3 V	1	2.8	4.7	0.5	5.6	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 10 pF (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	T_A = 25°C			T_A = −40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
t_{pd}	A, B, or C	Y	0.8 V		26.2				ns
			1.2 V ± 0.1 V	5.2	10.4	15.4	4.7	19.2	
			1.5 V ± 0.1 V	4	7.4	10.7	3.5	12.7	
			1.8 V ± 0.15 V	3.1	6	8.6	2.6	10.5	
			2.5 V ± 0.2 V	2.7	4.3	6.5	2.2	7.8	
			3.3 V ± 0.3 V	2.5	3.4	5.4	2	6.4	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	T_A = 25°C			T_A = −40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
t_{pd}	A, B, or C	Y	0.8 V		28.9				ns
			1.2 V ± 0.1 V	4.1	11.5	16.8	3.6	21.3	
			1.5 V ± 0.1 V	3	8.3	11.8	2.5	14.1	
			1.8 V ± 0.15 V	2.3	6.7	9.5	1.8	11.6	
			2.5 V ± 0.2 V	1.7	4.8	7.2	1.2	8.6	
			3.3 V ± 0.3 V	1.4	3.9	6	0.9	7.1	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 30 pF (unless otherwise noted) (see Figure 10 and Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	T_A = 25°C			T_A = −40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
t_{pd}	A, B, or C	Y	0.8 V		36.7				ns
			1.2 V ± 0.1 V	5.5	14.6	21.4	5	26.7	
			1.5 V ± 0.1 V	4.1	10.5	14.8	3.6	17.7	
			1.8 V ± 0.15 V	3.3	8.6	11.8	2.8	14.5	
			2.5 V ± 0.2 V	2.5	6.3	8.8	2	10.6	
			3.3 V ± 0.3 V	2.1	5.1	7.3	1.6	8.8	

OPERATING CHARACTERISTICS

$T_A = 25°C$

PARAMETER		TEST CONDITIONS	V_{CC}	TYP	UNIT
C_{pd}	Power dissipation capacitance	f = 10 MHz	0.8 V	4	pF
			1.2 V ± 0.1 V	4	
			1.5 V ± 0.1 V	4	
			1.8 V ± 0.15 V	4	
			2.5 V ± 0.2 V	4.4	
			3.3 V ± 0.3 V	4.8	

Product Folder Link(s): *SN74AUP1G97*

PARAMETER MEASUREMENT INFORMATION
(Propagation Delays, Setup and Hold Times, and Pulse Duration)

LOAD CIRCUIT

	V_{CC} = 0.8 V	V_{CC} = 1.2 V $\pm$ 0.1 V	V_{CC} = 1.5 V $\pm$ 0.1 V	V_{CC} = 1.8 V $\pm$ 0.15 V	V_{CC} = 2.5 V $\pm$ 0.2 V	V_{CC} = 3.3 V $\pm$ 0.3 V
C_L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V_M	V_{CC}/2	V_{CC}/2	V_{CC}/2	V_{CC}/2	V_{CC}/2	V_{CC}/2
V_I	V_{CC}	V_{CC}	V_{CC}	V_{CC}	V_{CC}	V_{CC}

VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS

VOLTAGE WAVEFORMS
PULSE DURATION

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, slew rate ≥ 1 V/ns.
C. The outputs are measured one at a time, with one transition per measurement.
D. t_{PLH} and t_{PHL} are the same as t_{pd}.
E. All parameters and waveforms are not applicable to all devices.

Figure 10. Load Circuit and Voltage Waveforms

Product Folder Link(s): *SN74AUP1G97*

PARAMETER MEASUREMENT INFORMATION
(Enable and Disable Times)
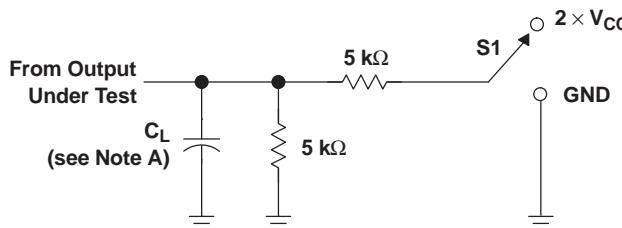
LOAD CIRCUIT

TEST	S1
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$
t_{PHZ}/t_{PZH}	GND

	$V_{CC} = 0.8$ V	$V_{CC} = 1.2$ V ± 0.1 V	$V_{CC} = 1.5$ V ± 0.1 V	$V_{CC} = 1.8$ V ± 0.15 V	$V_{CC} = 2.5$ V ± 0.2 V	$V_{CC} = 3.3$ V ± 0.3 V
C_L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V_M	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
V_I	V_{CC}	V_{CC}	V_{CC}	V_{CC}	V_{CC}	V_{CC}
V_Δ	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50$ Ω, slew rate ≥ 1 V/ns.
D. The outputs are measured one at a time, with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.
G. All parameters and waveforms are not applicable to all devices.

Figure 11. Load Circuit and Voltage Waveforms

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status [1]	Package Type	Package Drawing	Pins	Package Qty	Eco Plan [2]	Lead/Ball Finish	MSL Peak Temp [3]
SN74AUP1G97DBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DBVTE4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DCKTE4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DRLR	ACTIVE	SOT	DRL	6	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97DRLRG4	ACTIVE	SOT	DRL	6	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUP1G97YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74AUP1G97YZPR	ACTIVE	DSBGA	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS
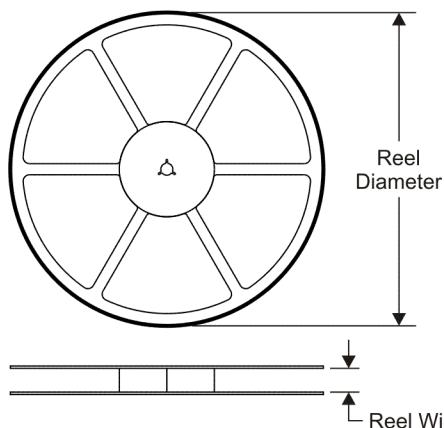
TAPE DIMENSIONS
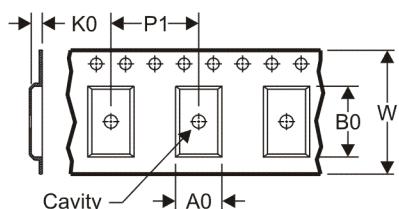
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

User Direction of Feed

Pocket Quadrants
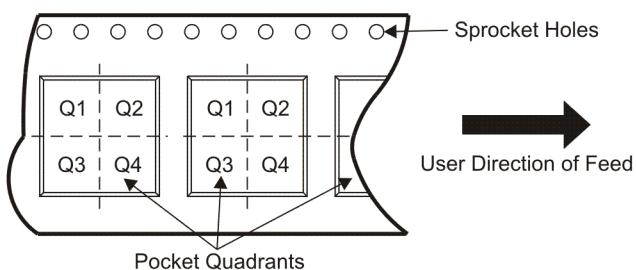
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G97DBVR	SOT-23	DBV	6	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G97DBVT	SOT-23	DBV	6	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G97DCKR	SC70	DCK	6	3000	180.0	8.4	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G97DCKT	SC70	DCK	6	250	180.0	8.4	2.24	2.34	1.22	4.0	8.0	Q3
SN74AUP1G97DRLR	SOT	DRL	6	4000	180.0	9.2	1.78	1.78	0.69	4.0	8.0	Q3
SN74AUP1G97YZPR	DSBGA	YZP	6	3000	178.0	8.4	1.02	1.52	0.63	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G97DBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
SN74AUP1G97DBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
SN74AUP1G97DCKR	SC70	DCK	6	3000	202.0	201.0	28.0
SN74AUP1G97DCKT	SC70	DCK	6	250	202.0	201.0	28.0
SN74AUP1G97DRLR	SOT	DRL	6	4000	202.0	201.0	28.0
SN74AUP1G97YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

DBV (R−PDSO−G6)   **PLASTIC SMALL−OUTLINE PACKAGE**
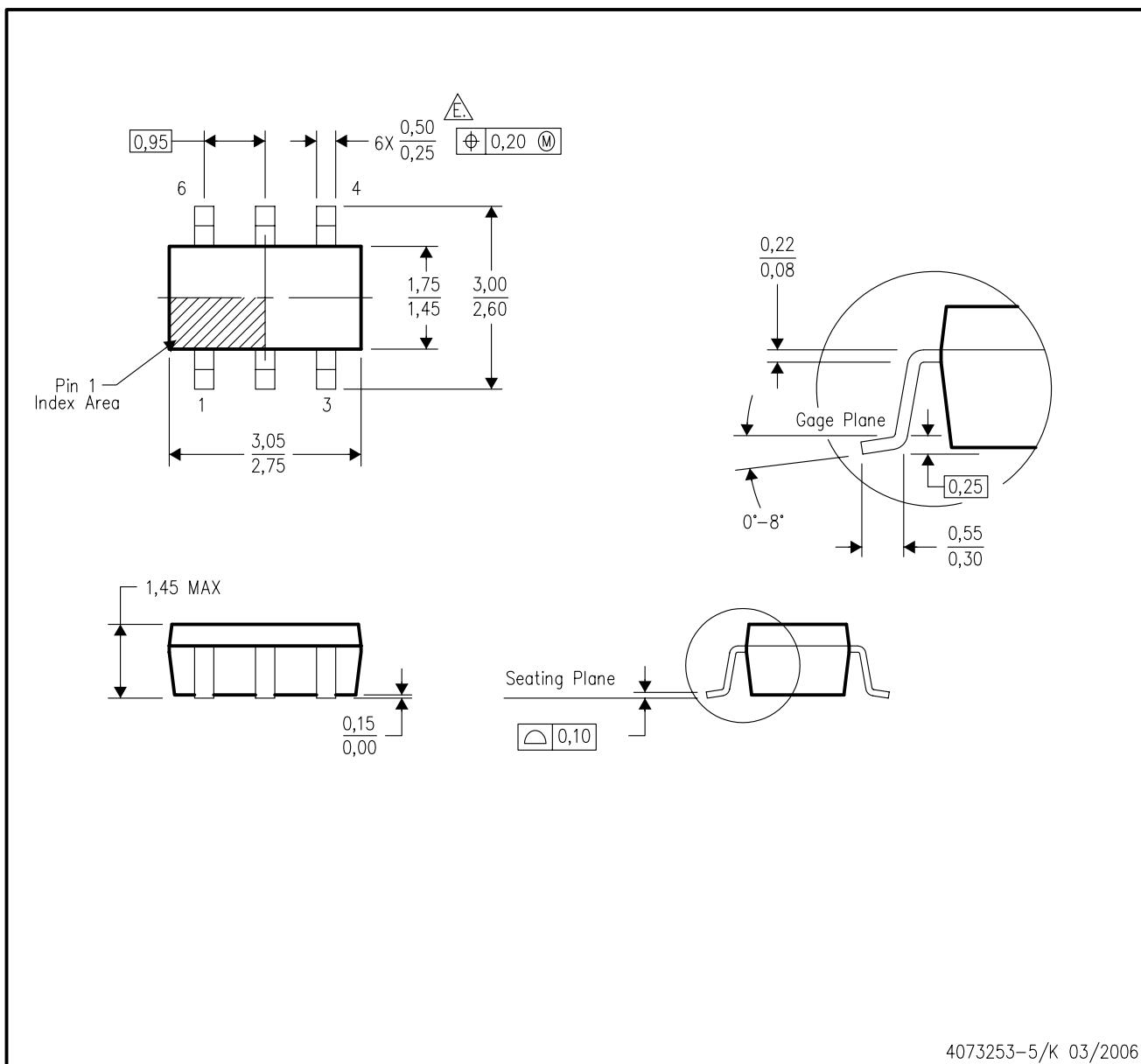
4073253−5/K 03/2006

NOTES: A.   All linear dimensions are in millimeters.
           B.   This drawing is subject to change without notice.
           C.   Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
           D.   Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
           E.   Falls within JEDEC MO−178 Variation AB, except minimum lead width.

YZP (R−XBGA−N6)   DIE−SIZE BALL GRID ARRAY

0,95
0,85   B

A

1,45
1,35

Ball A1 Index Area

0,50

0,25

C

B

A

1   2

Bottom View

1,00

0,50

6X Ø 0,25
       0,21

⊕ Ø 0,015 Ⓜ C A B

0,50 Max

0,05 C

Seating Plane

0,19
0,15

C

4204741−3/G   07/2008

NOTES: A.   All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
          B.   This drawing is subject to change without notice.
          C.   NanoFree™ package configuration.
          D.   This package is lead−free. Refer to the 6 YEP package (drawing 4204725) for tin−lead (SnPb).

NanoFree is a trademark of Texas Instruments.

TEXAS INSTRUMENTS
www.ti.com

DRL (R−PDSO−N6)

PLASTIC SMALL OUTLINE
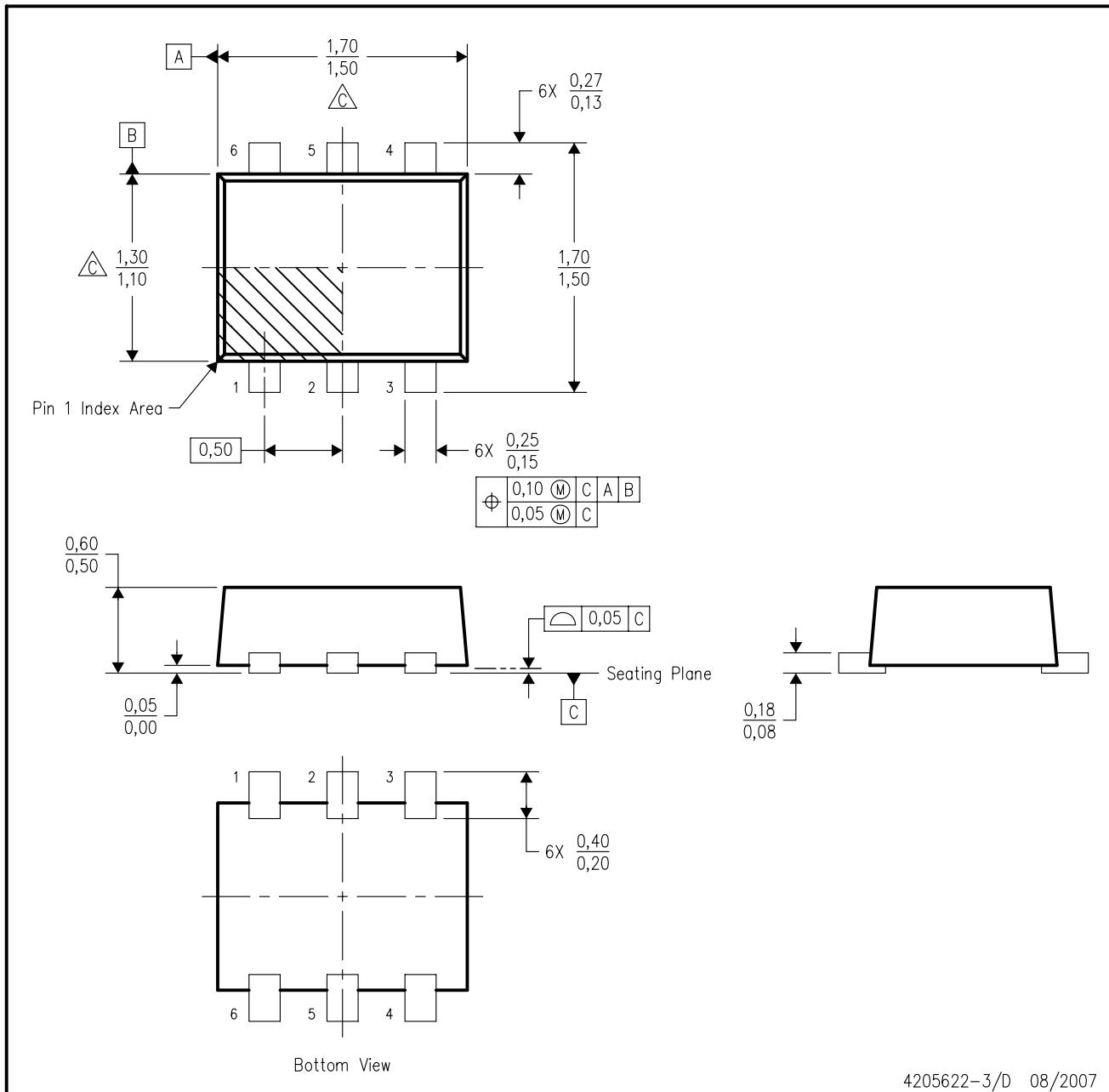
Pin 1 Index Area

Seating Plane

Bottom View

4205622−3/D   08/2007

NOTES: A.   All linear dimensions are in millimeters.   Dimensioning and tolerancing per ASME Y14.5M−1994.
         B.   This drawing is subject to change without notice.
         C.   Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.
              Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
         D.   JEDEC package registration is pending.

YFP (R−XBGA−N6)   DIE−SIZE BALL GRID ARRAY

0,80 / 0,74

A

B

1,20 / 1,14

— Ball A1 Index Area

0,40

0,20

C

B

A

1   2

0,80

0,40

Bottom View

6X Ø 0,25 / 0,21

⊕ Ø 0,015 Ⓜ C A B

0,50 Max

0,05 C

Seating Plane

C

0,17 / 0,13
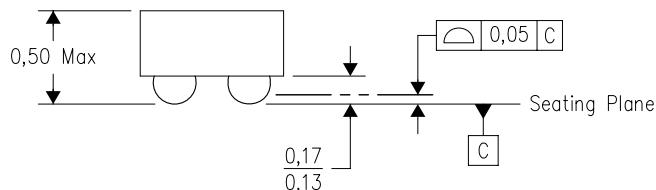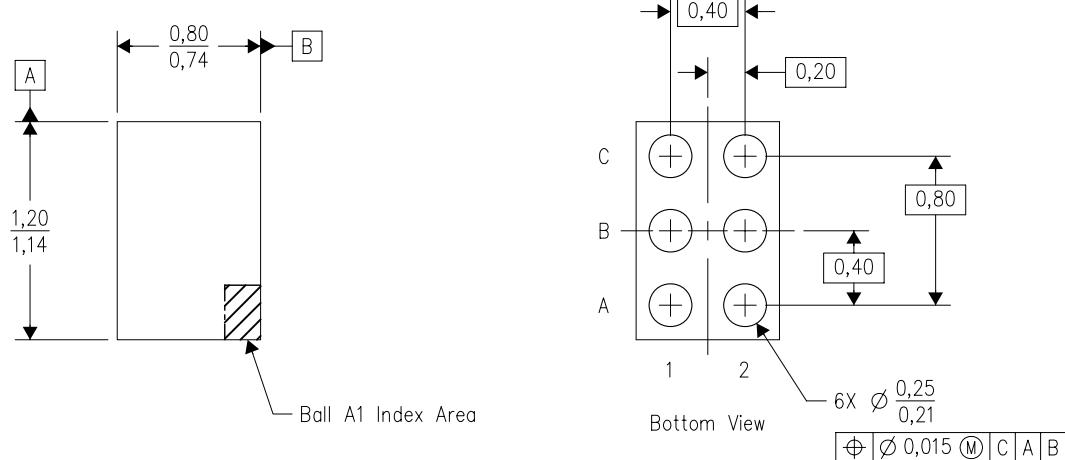
4206986−3/0 08/2008

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
        B. This drawing is subject to change without notice.
        C. NanoFree™ package configuration.
        D. This is a Pb−free solder ball design.

NanoFree is a trademark of Texas Instruments.

DCK (R−PDSO−G6)　　　PLASTIC SMALL−OUTLINE PACKAGE

2,15 / 1,85

2,40 / 1,80

1,40 / 1,10

6

4

1

3

Pin 1
Index Area

0,65

1,30

6X 0,30 / 0,15

⊕ 0,10 Ⓜ

0,22 / 0,08

Gauge Plane
Seating Plane

0,15

0°−8°

0,46 / 0,26

1,10 / 0,80

0,10

Seating Plane

0,10 / 0,00
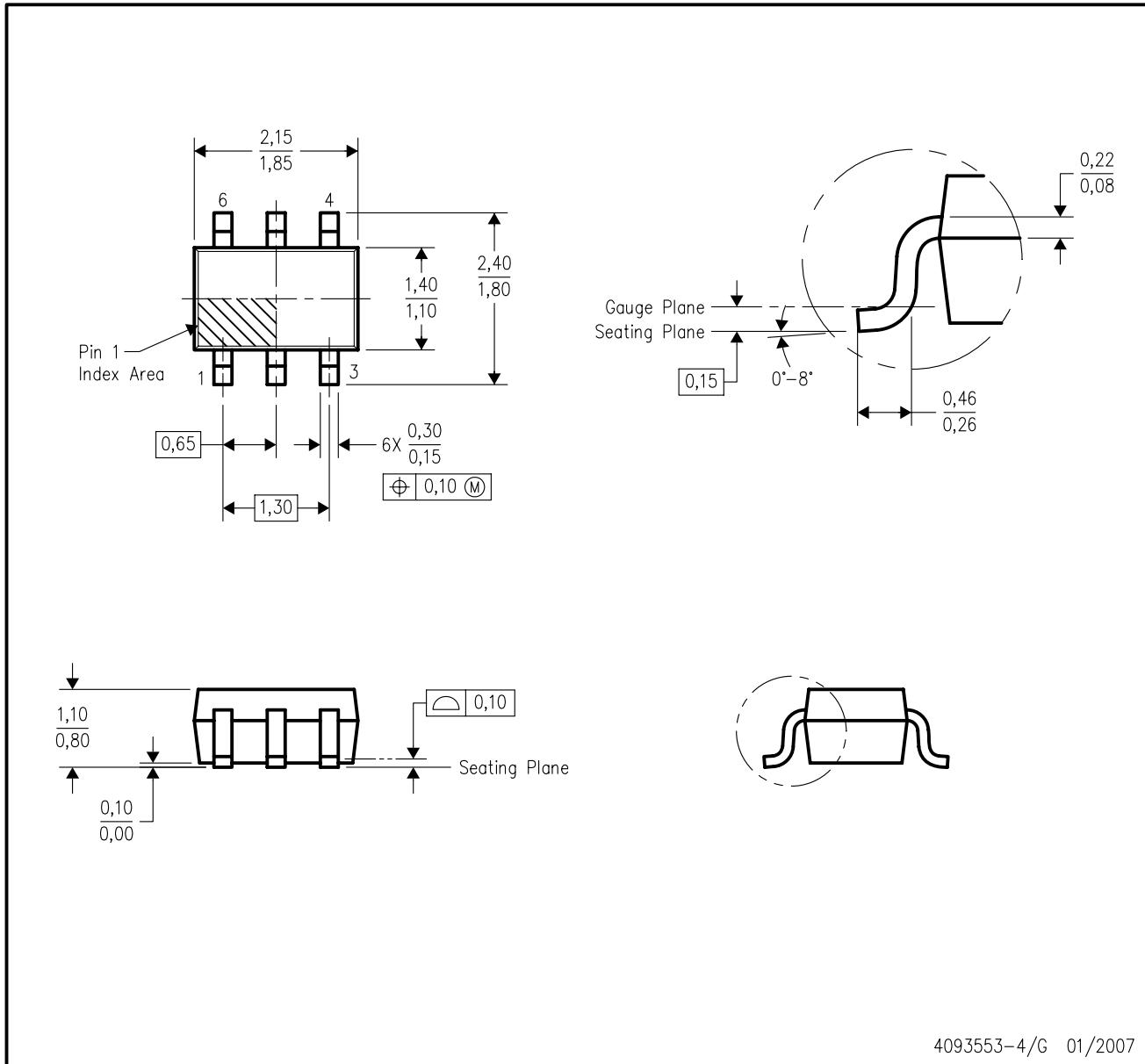
4093553−4/G　01/2007

NOTES:　A.　All linear dimensions are in millimeters.
　　　　　B.　This drawing is subject to change without notice.
　　　　　C.　Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
　　　　　D.　Falls within JEDEC MO−203 variation AB.

DCK (R−PDSO−G6)

Example Board Layout

Stencil Openings
Based on a stencil thickness
of .127mm (.005inch).

6x0,35

0,85

2,2

2,2

4x0,65

2x1,30

4x0,65

2x1,30

0,4

Solder Mask Opening

1,0 0,9

Pad Geometry

0,05

0,50
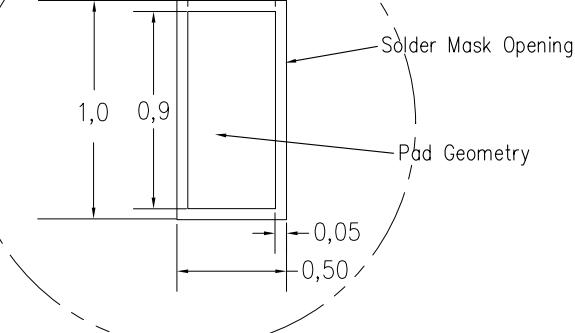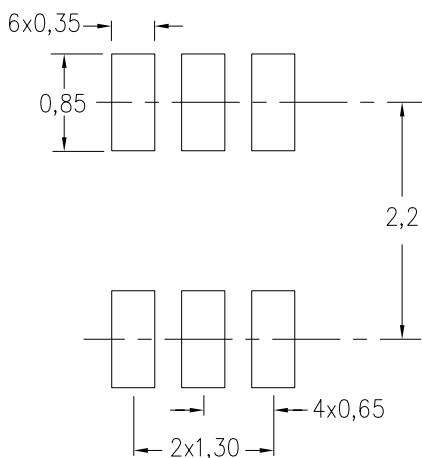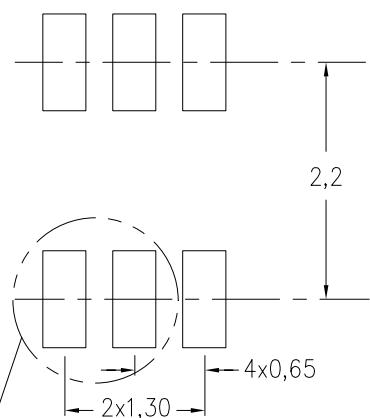
4210356/A 07/09

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC−7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC−7525 for other stencil recommendations.

IMPORTANT NOTICE